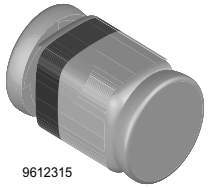
Small Signal Zener Diodes

Features

- Saving space
- Hermetic sealed parts
- Electrical data identical with the devices BZT55..Series / TZM..Series
- Fits onto SOD323/SOD110 footprints
- Very sharp reverse characteristic
- Low reverse current level
- Very high stability
- Low noise
- Available with tighter tolerances
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

- Voltage stabilization

Mechanical Data

Case: MicroMELF

Weight: approx. 12 mg

Packaging codes/options:

TR / 2.5 k per 7" reel, 12.5 k/box

TR3 / 10 k per 13" reel, 10 k/box

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Power dissipation	$R_{thJA} \leq 300$ K/W	P_V	500	mW
Z-current		I_Z	P_V/V_Z	mA
Junction temperature		T_j	175	°C
Storage temperature range		T_{stg}	- 65 to + 175	°C

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction to ambient air	mounted on epoxy-glass hard tissue, Fig. 1	R_{thJA}	500	K/W
Junction tie point	35 µm copper clad, 0.9 mm^2 copper area per electrode	R_{thJL}	300	K/W

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I_F = 200 mA	V_F			1.5	V

Electrical Characteristics

BZM55C..

Partnumber	Zener Voltage Range[1)]		Dynamic Resistance		Test Current	Temperature Coefficient		Test Current	Reverse Leakage Current		
	V_Z at I_{ZT}		r_{zjT} at I_{ZT}, f = 1kHz	r_{zjK} at I_{ZK}, f = 1kHz	I_{ZT}	TK_{VZ}		I_{ZK}	I_R at T_{amb} = 25 °C	I_R at T_{amb} = 150 °C	at V_R
	V		Ω		mA	%/K		mA	µA		V
	min	max				min	max				
BZM55C2V4	2.28	2.56	< 85	< 600	5	- 0.09	- 0.06	1	< 50	< 100	1
BZM55C2V7	2.5	2.9	< 85	< 600	5	- 0.09	- 0.06	1	< 10	< 50	1
BZM55C3V0	2.8	3.2	< 90	< 600	5	- 0.08	- 0.05	1	< 4	< 40	1
BZM55C3V3	3.1	3.5	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZM55C3V6	3.4	3.8	< 90	< 600	5	-0.08	- 0.05	1	< 2	< 40	1
BZM55C3V9	3.7	4.1	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZM55C4V3	4	4.6	< 90	< 600	5	- 0.06	- 0.03	1	< 1	< 20	1
BZM55C4V7	4.4	5	< 80	< 600	5	- 0.05	0.02	1	< 0.5	< 10	1
BZM55C5V1	4.8	5.4	< 60	< 550	5	- 0.02	0.02	1	< 0.1	< 2	1
BZM55C5V6	5.2	6	< 40	< 450	5	- 0.05	0.05	1	< 0.1	< 2	1
BZM55C6V2	5.8	6.6	< 10	< 200	5	0.03	0.06	1	< 0.1	< 2	2
BZM55C6V8	6.4	7.2	< 8	< 150	5	0.03	0.07	1	< 0.1	< 2	3
BZM55C7V5	7	7.9	< 7	< 50	5	0.03	0.07	1	< 0.1	< 2	5
BZM55C8V2	7.7	8.7	< 7	< 50	5	0.03	0.08	1	< 0.1	< 2	6.2
BZM55C9V1 *	8.5	9.6	< 10	< 50	5	0.03	0.09	1	< 0.1	< 2	6.8
BZM55C10 *	9.4	0.6	< 15	< 70	5	0.03	0.1	1	< 0.1	< 2	7.5
BZM55C11 *	10.4	11.6	< 20	< 70	5	0.03	0.11	1	< 0.1	< 2	8.2
BZM55C12 *	11.4	12.7	< 20	< 90	5	0.03	0.11	1	< 0.1	< 2	9.1
BZM55C13 *	12.4	14.1	< 26	< 110	5	0.03	0.11	1	< 0.1	< 2	10
BZM55C15 *	13.8	15.6	< 30	< 110	5	0.03	0.11	1	< 0.1	< 2	11
BZM55C16 *	15.3	17.1	< 40	< 170	5	0.03	0.11	1	< 0.1	< 2	12
BZM55C18 *	16.8	19.1	< 50	< 170	5	0.03	0.11	1	< 0.1	< 2	13
BZM55C20 *	18.8	21.2	< 55	< 220	5	0.03	0.11	1	< 0.1	< 2	15
BZM55C22 *	20.8	23.3	< 55	< 220	5	0.04	0.12	1	< 0.1	< 2	16
BZM55C24 *	22.8	25.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	18
BZM55C27 *	25.1	28.9	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	20
BZM55C30 *	28	32	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	22
BZM55C33 *	31	35	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	24
BZM55C36 *	34	38	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	27
BZM55C39 *	37	41	< 90	< 500	2.5	0.04	0.12	0.5	< 0.1	< 5	30
BZM55C43 *	40	46	< 90	< 600	2.5	0.04	0.12	0.5	< 0.1	< 5	33
BZM55C47 *	44	50	110	< 700	2.5	0.04	0.12	0.5	< 0.1	< 5	36
BZM55C51 *	48	54	125	< 700	2.5	0.04	0.12	0.5	< 0.1	< 10	39
BZM55C56 *	52	60	135	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	43
BZM55C62 *	58	66	150	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	47
BZM55C68 *	64	72	200	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	51
BZM55C75 *	70	79	250	< 1500	2.5	0.04	0.12	0.5	< 0.1	< 10	56

1) $t_p \leq 10$ ms, $T/t_p > 1000$

*) Additionnal measurement of Voltage group 9V1 to 75 at 95 % $V_{zmin} \leq 35$ nA at T_j 25 °C

Electrical Characteristics

BZM55B..

Partnumber	Zener Voltage Range[1)]		Dynamic Resistance		Test Current	Temperature Coefficient		Test Current	Reverse Leakage Current		
	V_Z at I_{ZT}		r_{zjT} at I_{ZT}, f = 1kHz	r_{zjK} at I_{ZK}, f = 1kHz	I_{ZT}	TK_{VZ}		I_{ZK}	I_R at T_{amb} = 25 °C	I_R at T_{amb} = 150 °C	at V_R
	V		Ω		mA	%/K		mA	µA		V
	min	max				min	max				
BZM55B2V4	2.35	2.45	< 85	< 600	5	- 0.09	- 0.06	1	< 50	< 100	1
BZM55B2V7	2.64	2.76	< 85	< 600	5	- 0.09	- 0.06	1	< 10	< 50	1
BZM55B3V0	2.94	3.06	< 90	< 600	5	- 0.08	- 0.05	1	< 4	< 40	1
BZM55B3V3	3.24	3.36	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZM55B3V6	3.52	3.68	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZM55B3V9	3.82	3.98	< 90	< 600	5	- 0.08	- 0.05	1	< 2	< 40	1
BZM55B4V3	4.22	4.38	< 90	< 600	5	- 0.06	- 0.03	1	< 1	< 20	1
BZM55B4V7	4.6	4.80	< 80	< 600	5	- 0.05	0.02	1	< 0.5	< 10	1
BZM55B5V1	5	5.20	< 60	< 550	5	- 0.02	0.02	1	< 0.1	< 2	1
BZM55B5V6	5.48	5.72	< 40	< 450	5	- 0.05	0.05	1	< 0.1	< 2	1
BZM55B6V2	6.08	6.32	< 10	< 200	5	0.03	0.06	1	< 0.1	< 2	2
BZM55B6V8	6.66	6.94	< 8	< 150	5	0.03	0.07	1	< 0.1	< 2	3
BZM55B7V5	7.35	7.65	< 7	< 50	5	0.03	0.07	1	< 0.1	< 2	5
BZM55B8V2	8.04	8.36	< 7	< 50	5	0.03	0.08	1	< 0.1	< 2	6.2
BZM55B9V1 *	8.92	9.28	< 10	< 50	5	0.03	0.09	1	< 0.1	< 2	6.8
BZM55B10 *	9.8	10.20	< 15	< 70	5	0.03	0.1	1	< 0.1	< 2	7.5
BZM55B11 *	10.78	11.22	< 20	< 70	5	0.03	0.11	1	< 0.1	< 2	8.2
BZM55B12 *	11.76	12.24	< 20	< 90	5	0.03	0.11	1	< 0.1	< 2	9.1
BZM55B13 *	12.74	13.26	< 26	< 110	5	0.03	0.11	1	< 0.1	< 2	10
BZM55B15 *	14.7	15.30	< 30	< 110	5	0.03	0.11	1	< 0.1	< 2	11
BZM55B16 *	15.7	16.30	< 40	< 170	5	0.03	0.11	1	< 0.1	< 2	12
BZM55B18 *	17.64	18.36	< 50	< 170	5	0.03	0.11	1	< 0.1	< 2	13
BZM55B20 *	19.6	20.40	< 55	< 220	5	0.03	0.11	1	< 0.1	< 2	15
BZM55B22 *	21.55	22.45	< 55	< 220	5	0.04	0.12	1	< 0.1	< 2	16
BZM55B24 *	23.5	24.5	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	18
BZM55B27 *	26.4	27.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	20
BZM55B30 *	29.4	30.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	22
BZM55B33 *	32.4	33.6	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	24
BZM55B36 *	35.3	36.7	< 80	< 220	5	0.04	0.12	1	< 0.1	< 2	27
BZM55B39 *	38.2	39.8	< 90	< 500	2.5	0.04	0.12	1	< 0.1	< 5	30
BZM55B43 *	42.1	43.9	< 90	< 600	2.5	0.04	0.12	0.5	< 0.1	< 5	33
BZM55B47 *	46.1	47.9	< 110	< 700	2.5	0.04	0.12	0.5	< 0.1	< 5	36
BZM55B51 *	50	52.0	< 125	< 700	2.5	0.04	0.12	0.5	< 0.1	< 10	39
BZM55B56 *	54.9	57.1	< 135	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	43
BZM55B62 *	60.8	63.2	< 150	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	47
BZM55B68 *	66.6	69.4	< 200	< 1000	2.5	0.04	0.12	0.5	< 0.1	< 10	51
BZM55C75 *	73.5	76.5	< 250	< 1500	2.5	0.04	0.12	0.5	< 0.1	< 10	56

[1)] $t_p \leq 10$ ms, $T/t_p > 1000$

[*)] Additionnal measurement of Voltage group 9V1 to 75 at 95 % $V_{zmin} \leq 35$ nA at T_j 25 °C

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

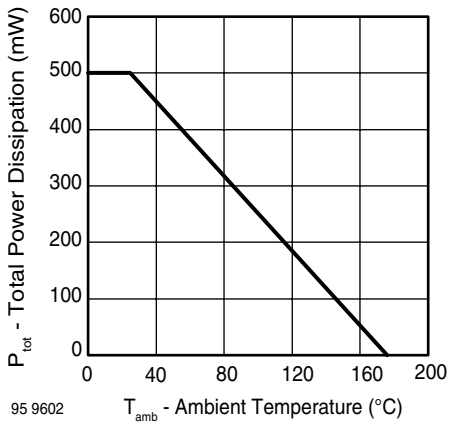


Figure 1. Total Power Dissipation vs. Ambient Temperature

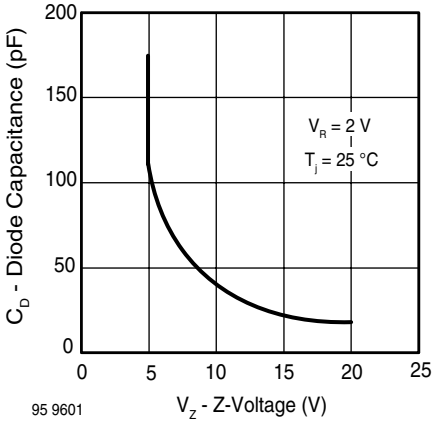


Figure 4. Diode Capacitance vs. Z-Voltage

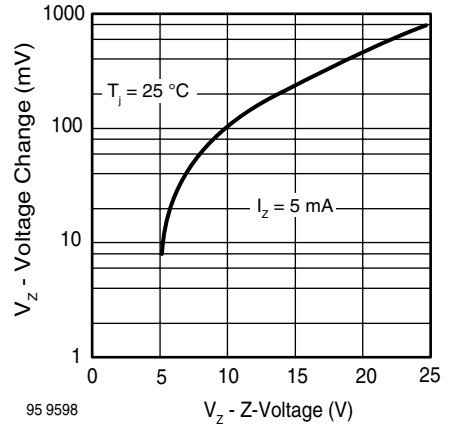


Figure 2. Typical Change of Working Voltage under Operating Conditions at T_{amb}=25°C

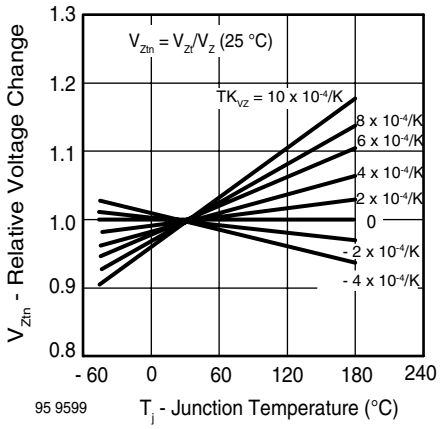


Figure 5. Typical Change of Working Voltage vs. Junction Temperature

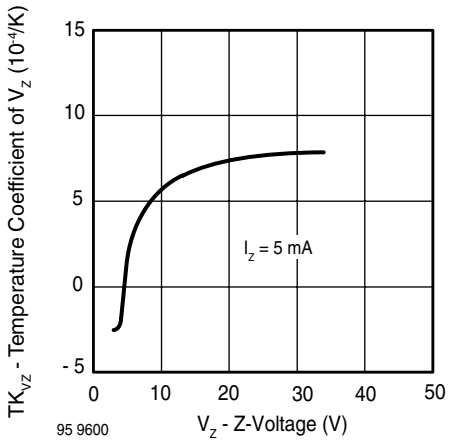


Figure 3. Temperature Coefficient of Vz vs. Z-Voltage

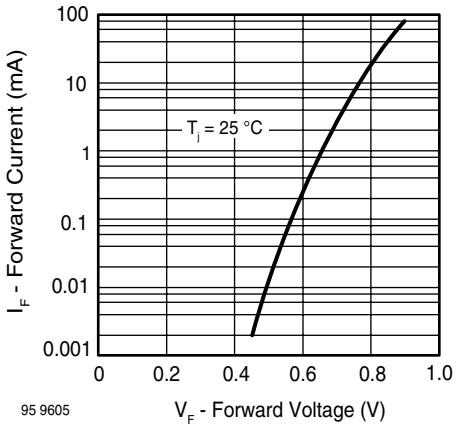


Figure 6. Forward Current vs. Forward Voltage

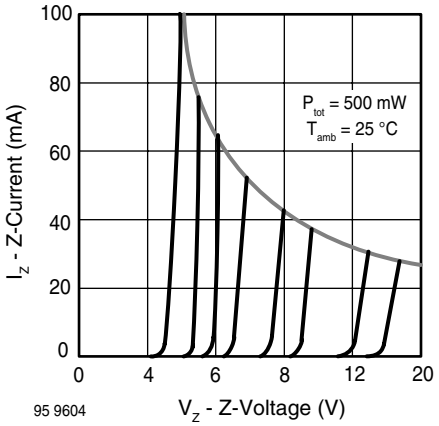


Figure 7. Z-Current vs. Z-Voltage

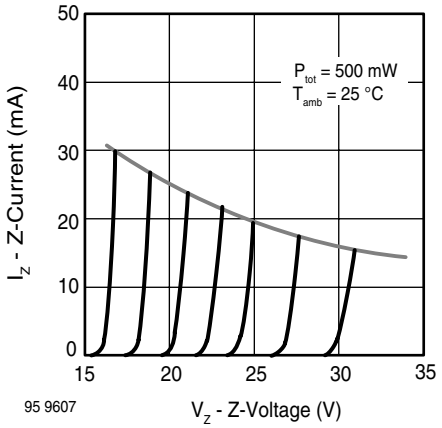


Figure 8. Z-Current vs. Z-Voltage

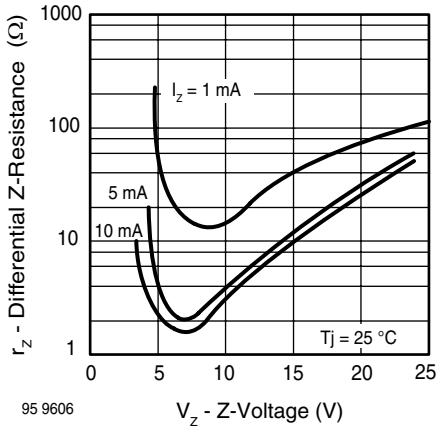


Figure 9. Differential Z-Resistance vs. Z-Voltage

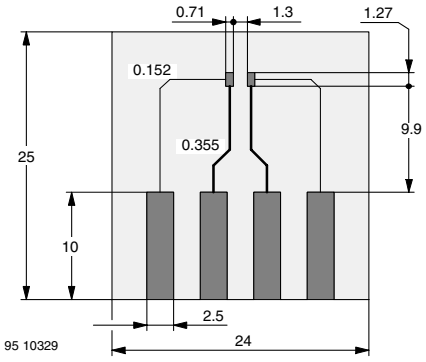


Figure 10. Board for R_{thJA} definition (in mm)

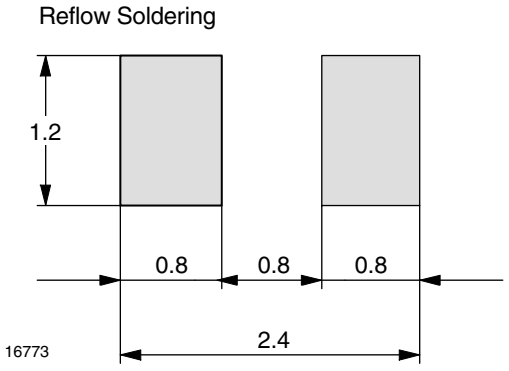


Figure 11. Recommended foot pads (in mm)

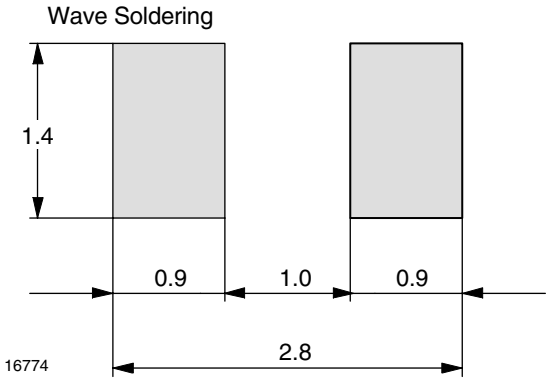


Figure 12. Recommended foot pads (in mm)

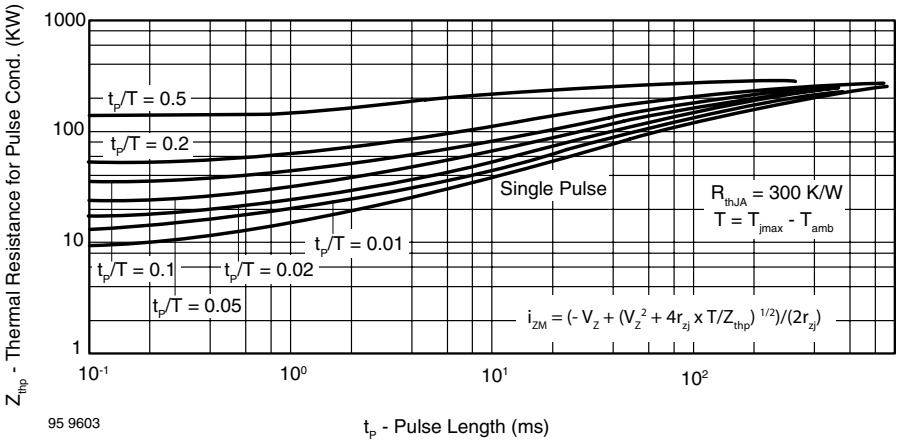
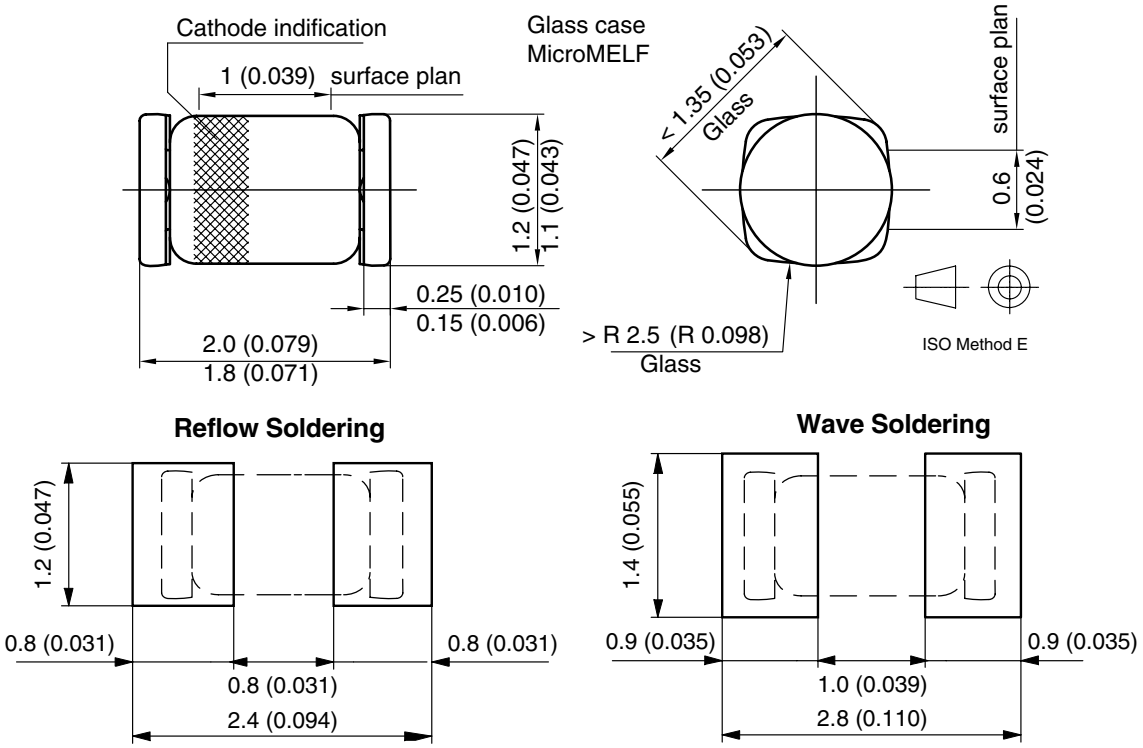


Figure 13. Thermal Response

Package Dimensions in mm (Inches)



Document No.: 6.560-5007.01-4
Rev. 11, 07.Feb.2005
9612072

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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